

VCO-112S/STC

HIGH RELIABILITY MILITARY AND SPACE VCO

Package: Module, 22.86mmx22.86mmx13.97mm

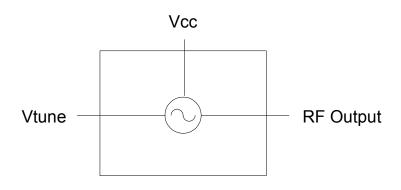


Features

- 2000 MHz to 3200 MHz VCO
- 15V Operation
- +12.5dBm Typical Output Power
- -85dBc/Hz at 10kHz
- -105 dBc/Hz at 100 kHz
- -128dBc/Hz at 1000kHz

Applications

- Instrumentation
- Aerospace
- Test Equipment
- Plug and Play



Functional Block Diagram

Product Description

RFMD's VCO-112S/STC is a hybrid assembled voltage controlled oscillator integrated into a connectorized module. The VCO-112 features an integrated resonator and tuning varactors. The part features excellent performance over temperature.

Ordering Information

VCO-112S/STC High Reliability Military and Space VCO

Optimum Technology Matching® Applied ☐ GaAs HBT ☐ SiGe BiCMOS ☐ GaAs pHEMT ☐ GaN HEMT ☐ GaAs MESFET ☐ Si BiCMOS ☐ Si CMOS ☐ BIFET HBT ☐ InGaP HBT ☐ SiGe HBT ☑ Si BJT ☐ LDMOS

VCO-112S/STC



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{CC})	17	V
V _{TUNE}	0 to 22	V
Storage Temperature	-65 to 150	°C
Operating Temperature	-55 to 100	°C
ESD JESD22 - A114 Human Body Model (HBM)		V



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

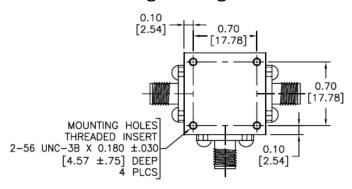
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Parameter	Specification		11	O a rediki a re		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Frequency						
Frequency Range	2000		3200	MHz	100% Production Tested	
Tuning Voltage						
2000MHz	0	1.5		V _{DC}	100% Production Tested	
3200MHz		18.0	20	V _{DC}	100% Production Tested	
Tuning Sensitivity						
2000 MHz	44	58	73	MHz/V	100% Production Tested	
2300 MHz	55	73	92	MHz/V	100% Production Tested	
2600 MHz	106	142	178	MHz/V	100% Production Tested	
2900 MHz	65	87	109	MHz/V	100% Production Tested	
3200 MHz	35	47	59	MHz/V	100% Production Tested	
Output Power	10	12.5	16	dBm	100% Production Tested	
Output Phase Noise						
10 kHz		-85	-79	dBc/Hz	100% Production Tested	
100 kHz		-105	-99	dBc/Hz	100% Production Tested	
1000 kHz		-128	-122	dBc/Hz	100% Production Tested	
Power Supply	14.75	15	15.25	V	100% Production Tested	
Supply Current		19	22.0	mA	100% Production Tested	
Harmonic Suppression						
2nd Harmonic		-15	-10	dBc	100% Production Tested	
3rd Harmonic		-18	-10	dBc	100% Production Tested	
Spurious (Non-Harmonic)			-80	dBc		
Frequency Pushing		1	2.5	MHz p-p	14.75V to 15.25V	
Frequency Pulling		40	50	MHz p-p	20dB RL	
Output Impedance		50		Ω		
3dB Modulation Bandwidth	20000	35000		kHz	$Z_G = 50\Omega$	
Tune Port Impedance		50		kΩ		



Pin	Function	Description
1	VTUNE	Tuning voltage.
2	VCC	Supply voltage.
3	RF Output	VCO RF output.

Pin Out and Package Drawing



0.55

PINOUT	FUNCTION			
PIN	vco	MIXER	POWER DIVIDER	
1	TUNING VOLTAGE	RF PORT	OUT 2	
2	SUPPLY VOLTAGE	X PORT	IN	
3	RF OUTPUT	LO PORT	OUT 1	

